

CMOS 4-Bit D-Type Registers

High-Voltage Types (20-Volt Rating)

■ CD4076B types are four-bit registers consisting of D-type flip-flops that feature three-state outputs. Data Disable inputs are provided to control the entry of data into the flip-flops. When both Data Disable inputs are low, data at the D inputs are loaded into their respective flip-flops on the next positive transition of the clock input. Output Disable inputs are also provided. When the Output Disable inputs are both low, the normal logic states of the four outputs are available to the load. The outputs are disabled independently of the clock by a high logic level at either. Output Disable input, and present a high impedance.

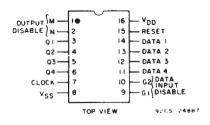
The CD4076B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

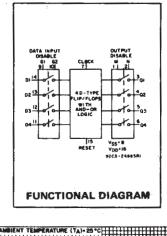
- Three-state outputs
- Input disabled without gating the clock
- Gated output control lines for enabling or disabling the outputs
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25^oC
- Noise margin over full package temperature range:

	1	۷	at	VDD	=	5 \	/
	2	۷	at	VDD	=	10	V
2	5	v	-	Vnn	_	15	1

- 2.5 V at V_{DD} = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



TERMINAL ASSIGNMENT



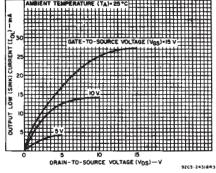


Fig.1 - Typical output low (sink) current characteristics.

RECOMMENDED OPERATING CONDITIONS at T_A = 25°C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD}	LIN	AITS	UNITS
	(V)	Min.	Max.	
Supply Voltage Range (For T _A =Full Package Temperature Range)		3	18	v
	5	200 80		ns
Data Setup Time, t _S	10 15	60		115
	5	200	-	
Clock Pulse Width, tw	10	100		ns
	15	80	-	
	5		3	
Clock Input Frequency, fCL	10	dc	6	MHz
	15		8	
	5		15	
Clock Input Bise or Fall Time, trCL, tfCL	10	-	5	μs
	15		5	
	5	120		
Reset Pulse Width, tw	10	50		ns
	15	40	·	
	5	180	-	
Data Input Disable Setup Time, tS	10	100	-	ns
	15	70	_	

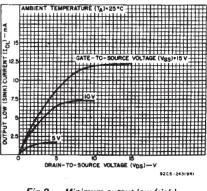
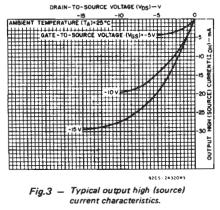


Fig.2 — Minimum output low (sink) current characteristics.



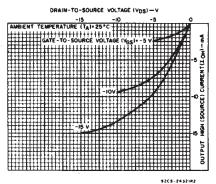
CD4076B Types

CD4076B Types

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MAXIMUM RATINGS, Absolute-Maximum Values:

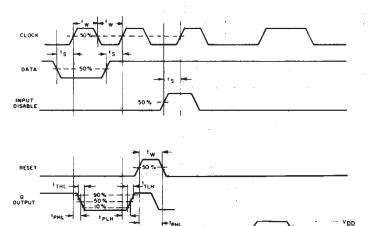
DC SUPPLY-VOLTAGE RANGE, (V _{DD}) Voltages referenced to V _{SS} Terminal)
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C
STORAGE TEMPERATURE RANGE (T _{stg})65°C to +150°C
LEAD TEMPERATURE (DURING SOLDĚRING):
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max



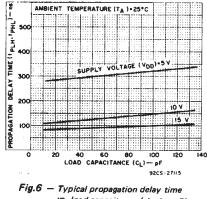
- Minimum output high (source)

current characteristics.

Fig.4

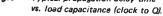


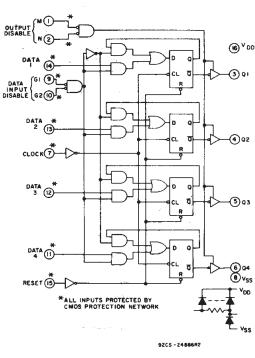
OUTPUT DISABLE

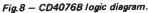


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COMMERCIAL CMOS HIGH VOLTAGE ICs









50 **'**

10%

90%

CHAR.

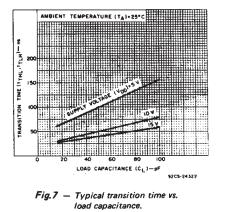
† PHZ

† PLZ

† PH 7 🖓 🍽

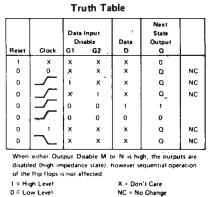
Q OUTPUT

Q OUTPUT



92CM-24688R2

(a)



155

Voi

∀он

Vss

9205-29299

(b)

PZL VDD

*PZH

0.%

TEST VOLT.

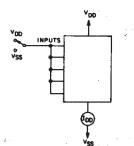
AT D AT Q VDD VSS

PLZ VSS VDD PZL VSS VDD

TPZH VDD VSS

CHARACTERISTIC	TEST CONDI	TIONS	LIMITS			UNITS	
		V _{DD} V	Min.	Тур.	Max.		
Propagation Delay Time:		5		300	600	<u> </u>	
Clock to Q Output, tpHL, tpEH	. :	10		125	250		
		15		90	180	1	
		5 😳	· ·	230	460	l et er	
Reset, tPHL		10		100	200		
PHL 1		15		75	150		
· · · · · · · · · · · · · · · · · · ·	···	50	1	150	300	ns	
3-State Output 1 or 0 to High	$R_{L} = 1 k \Omega$	10		75	150		
Impedance, tpHZ, tpLZ	112-1832	15		60	120		
		5		150	300	1	
3 State High Impedance to 1	$R_L = 1 \kappa \Omega$	10		75	150		
or 0 Output, tpzH, tpzL		15		60	120		
· · · · · · · · · · · · · · · · · · ·		5		100	200		
Transition Time, TTHL TTLH		10		50	100	ns	
HUMBER AND		15		40	80		
		5	3	6			
Maximum Clock Input Frequency, fcL		10	6	12		MHZ	
		15	8	16			
		5		100	200		
Minimum Clock Pulse Width, tw		10		50	100	ns.	
		15		40	80		
Maniana Charle ta a t							
Maximum Clock Input Rise or Fall Time,		5 10	15 5	-	-		
¹ ^t rcl ^{, t} fcl		15	5			μs	
		5	. •	60	120		
Minimum Reset Pulse With, t _W		10		25	50	ns	
		15		20	40		
		5		100	200		
Minimum Data Setup Time, t _S		10	-	40	80	ns	
		15		30	60		
Minimum Data Input Disable		5	-	90	180		
Setup Time, t _S		10	-	50	100	ns	
		15		35	70		
Input Capacitance, CIN	Any Input	$\frac{1}{\sqrt{2}}$	-	5	7.5	pF	

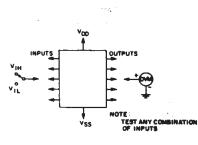
DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25⁰C, Input t_r,t_f = 20 ns, the state of the

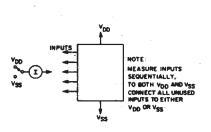


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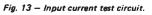


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 $(\gamma_{1},\gamma_{1},\ldots,\gamma_{n},\gamma_{n})$

Fig.11 - Quiescent device current test circuit.

Fig.12 – Input voltage test circuit.



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STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONI	DITIO	NS	LIMI	LIMITS AT INDICATED TEMPERATURES (°C)									
ISTIC	Vo	VIN	VDD						UNITS					
	(V) :	(V)	(V)	-55	40	+85	+125	Min.	Typ.	Max.				
Quiescent Device	. .	0,5	5	5	5	150	150		0.04	5				
Current, IDD Max.	-	0,10	10	10	10	300	300	-	0.04	10	μA			
		0,15	15	20	20	600	600	·	0.04	20				
	-	0,20	20	100	100	3000	3000	-	0.08	100	1			
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-				
(Sink) Current	0,5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	i '			
10L Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	-	1			
Output High (Source) Current, IOH Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0,51	-1	<u> </u>	mA			
	2,5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	1			
	9.5	0,10	10	-1.6	-1.5	1.1	-0.9	-1.3	-2.6	-	1			
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	3.4	-6.8	-				
Output Voltage:	-	0,5	5,		0	.05		-	0	0.05				
Low-Level,	_	0,10	10		0	.05		_	0	0.05				
VOL Max		0,15	15		0	.05			0	0.05				
Output Voltage:	-	0,5	5		- 4	95		4.95	5	- 1	V			
High-Level,	-	0,10	10		9	95		9.95	10	-				
VOH Min.		0,15	15		14	.95		14.95	15	-				
Input Low	0.5, 4.5	-	5		1	.5			- 1	1.5				
Voltage,	1, 9		10			3		_	-	3				
VIL Max.	1.5,13.5	_	15			4		-	—	4				
Input High	0.5, 4.5		5		3	.5		3.5	-		V .			
Voltage,	1, 9	_	10			7		7	-					
VIH Min.	1.5,13.5	~	15		1	1		11	_	-				
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA			
3-State Output Leakage Current IOUT Max	0,18	0,18	18	±0.4	±0.4	±12	±12	-	±104	±0.4	μΑ			

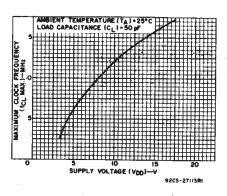


Fig.9 - Typical maximum clock input frequency vs. supply voltage.

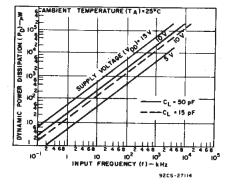
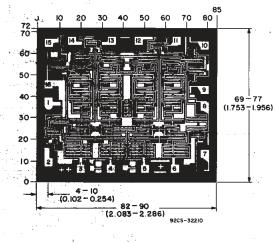


Fig. 10 — Typical dynamic power dissipation vs. frequency.



Dimensions and pad layout for CD4076BH

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Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .





PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•		Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material (6)	(3)		(4/5)	
CD4076BE	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4076BE	Samples
CD4076BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4076BF	Samples
CD4076BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4076BF3A	Samples
CD4076BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4076BM	Samples
CD4076BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4076BM	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF CD4076B, CD4076B-MIL :

- Catalog : CD4076B
- Military : CD4076B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



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9-Mar-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD4076BE	Ν	PDIP	16	25	506	13.97	11230	4.32
CD4076BE	Ν	PDIP	16	25	506	13.97	11230	4.32
CD4076BM	D	SOIC	16	40	507	8	3940	4.32

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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